

G1A-G1M

1.0AMP SURFACE MOUNT GLASS RECOVERY RECTIFIER

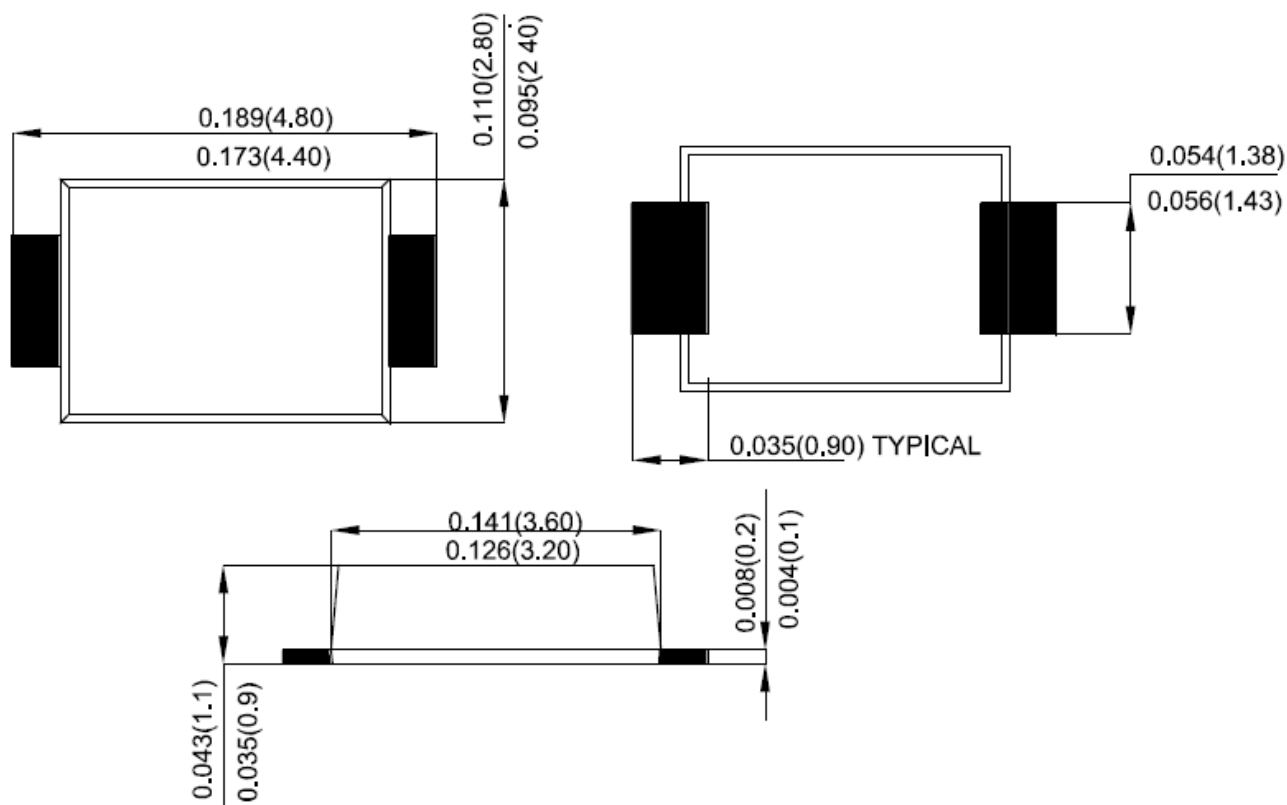
Features:

- For surface mounted application
- Low forward voltage drop
- High current capability
- High reliability
- Classification Rating 94V- 0

Mechanical Data:

- Case: SMAF, Molded plastic
- Terminals: Plated leads solderable per MIL-STD-750, Method 2026 guaranteed
- Polarity: Color band denotes cathode end
- Mounting Position: Any
- Marking: Type Number

Mechanical Dimensions: In Inches/mm



SMAF

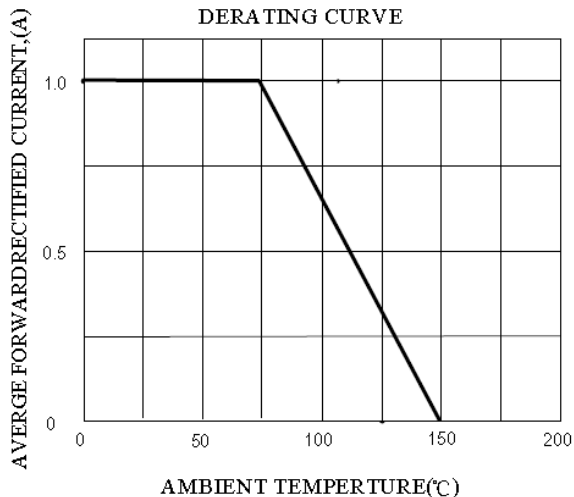
- China - Germany - Korea - Singapore - United States •
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Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

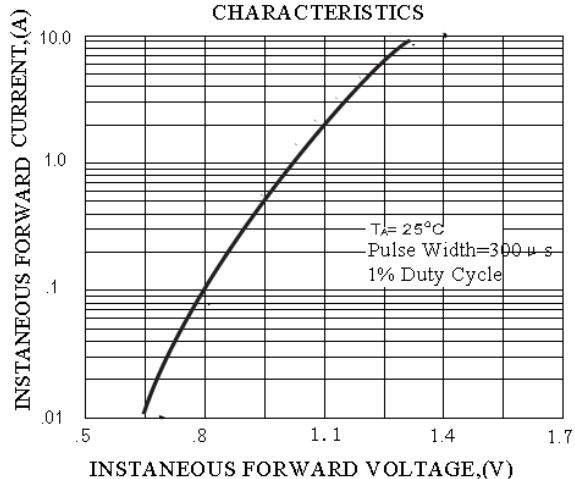
Type Number	Symbol	G1A	G1B	G1D	G1G	G1J	G1K	G1M	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_{DC}	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Average forward rectified output current @T _A = 75°C	I _O	1.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	35							A
Forward Voltage @I _F = 1.0A	V _F	1.1							V
Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 100°C	I _{RM}	5.0 500							μA
Typical Junction Capacitance (Note 1)	C _J	12							pF
Typical Thermal Resistance Junction to Ambient (Note 2)	R _{θJA}	30							°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150							°C
Case Style	SMAF								

Note: 1. Measured at 1.0 MHz and Applied reverse Voltage of 4.0V D.C
2. Resistance from Junction to Ambient at 0.375(9.5mm) lead length .

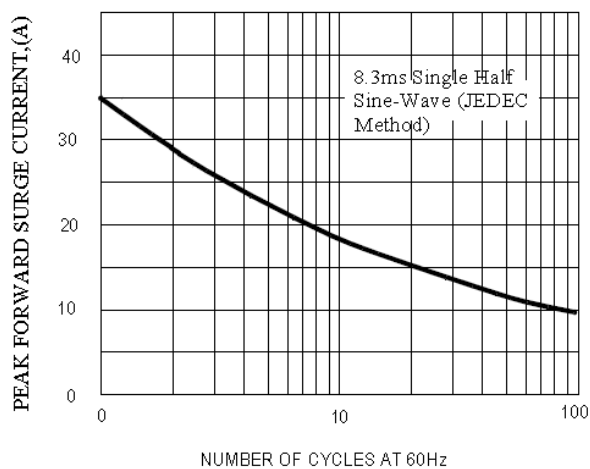
**FIG.1-TYPICAL FORWARD CURRENT
DERATING CURVE**



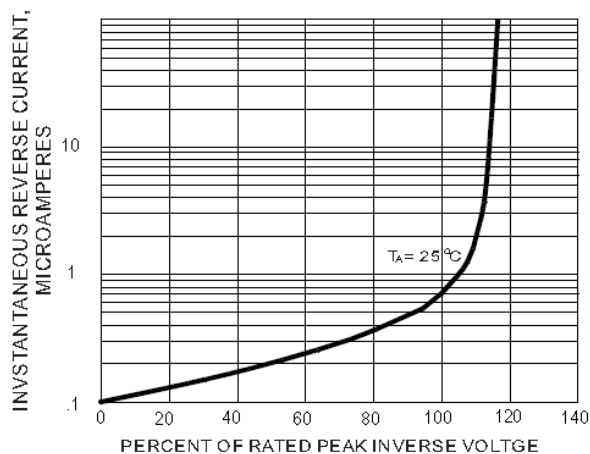
**FIG.2-TYPICAL INSTANTANEOUS FORWARD
CHARACTERISTICS**



**FIG.3-MAXIMUM NON-REPETITIVE
FORWARD SURGE CURRENT**



**FIG.4-TYPICAL REVERSE
CHARACTERISTICS**



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